

# UNISONIC TECHNOLOGIES CO., LTD

BAS21 DIODE

# GENERAL PURPOSE DIODES

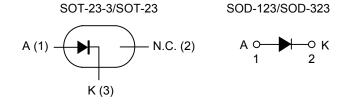
#### ■ DESCRIPTION

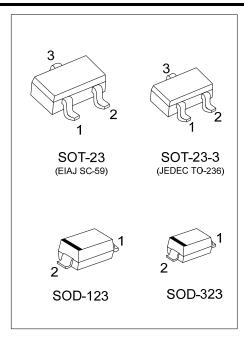
The UTC **BAS21** is a general purpose diode using UTC's planar technology to provide customers with high current capacity and high switching speed.

# ■ FEATURES

- \* High Current Capability
- \* High Switching Speed

#### ■ SYMBOL

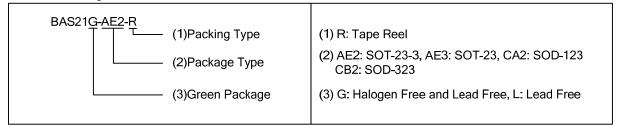




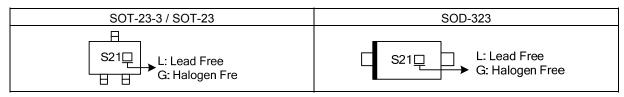
# ■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BAS21L-AE2-R	BAS21G-AE2-R	SOT-23-3	Α	NC	K	Tape Reel	
BAS21L-AE3-R	BAS21G-AE3-R	SOT-23	Α	NC	K	Tape Reel	
BAS21L-CA2-R	BAS21G-CA2-R	SOD-123	Α	K	NC	Tape Reel	
BAS21L-CB2-R	BAS21G-CB2-R	SOD-323	Α	K	NC	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode NC: No Connection



#### MARKING



<u>www.unisonic.com.tw</u> 1 of 3

BAS21 DIODE

# ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage		$V_{RRM}$	250	V
Continuous Reverse Voltage		$V_R$	200	V
Continuous Forward Current (Note 1)		l <sub>F</sub>	200	mA
Repetitive Peak Forward Current		I <sub>FRM</sub>	625	mA
Non-Repetitive Peak Forward	t=1µs		9	Α
Current (Square Wave,	t=100µs	I <sub>FSM</sub>	3	Α
T <sub>J</sub> =25 °C Prior to Surge)	t=10ms		1.7	Α
Power Dissipation (T <sub>A</sub> =25°C) (Note 1)	SOT-23 SOT-23-3	P <sub>D</sub>	250	mW
	SOD-123 SOD-323		410	mW
Junction Temperature		ΤJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL CHARACTERISTICS

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 1)	SOT-23 SOT-23-3	0	330	K/W
	SOD-123 SOD-323	$ heta_{JA}$	200	K/W

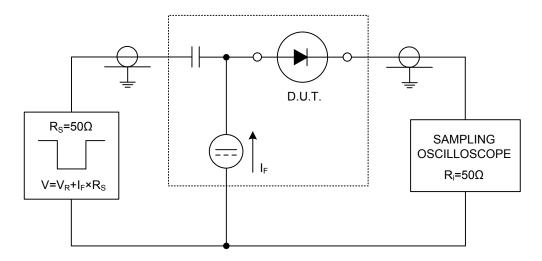
Note: 1. Device mounted on an FR4 printed-circuit board.

# ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified.)

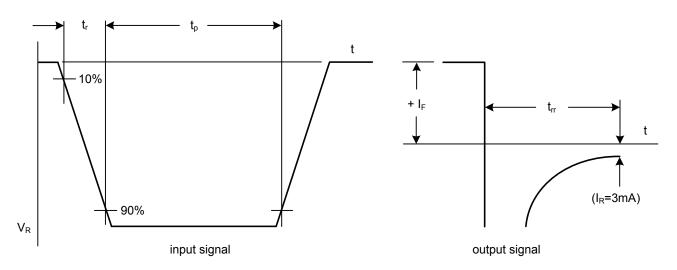
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage	l V⊏	I <sub>F</sub> =100mA			1	V
		I <sub>F</sub> =200mA			1.25	V
Reverse Current	ln l	V <sub>R</sub> =200V			100	nA
		V <sub>R</sub> =200V, T <sub>J</sub> =150°C			100	μΑ
Diode Capacitance	$C_D$	f=1MHz, V <sub>R</sub> =0			5	рF
Reverse Recovery Time	t <sub>DD</sub>	when switched from $I_F$ =30mA to $I_R$ =30mA, $R_L$ =100 $\Omega$ , measured at $I_R$ =3mA			50	ns

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#### ■ TEST CIRCUITS AND WAVEFOMS



Reverse recovery voltage test circuit



Reverse recovery voltage waveforms

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